

N-Channel 80 V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A) ^a	Q _g (Typ.)	
80	0.075 at V _{GS} = 10 V	3.5	7.3 nC	
00			7.5110	

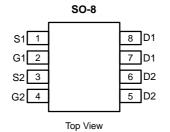
FEATURES

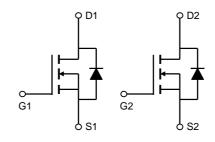
- DT-Trench Power MOSFET
- 100 % R_g and UIS Tested
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

DC/DC Conversion

- Notebook System Power





Absolute Maximum Ratings T _A =25°C unless otherwise noted					
Parameter		Symbol	Maximum	Units	
Drain-Source Voltage		V _{DS}	80	V	
Gate-Source Voltage		V _{GS}	±30	V	
Continuous Drain	T _A =25℃	1	3.5		
Current	T _A =70℃	'D	2.9	А	
Pulsed Drain Current ^C		I _{DM}	18		
Avalanche Current ^C		I _{AR}	16	А	
Repetitive avalanche energy L=0.1mH ^C		E _{AR}	12.8	mJ	
Power Dissipation ^B	T _A =25℃	D	2	W	
	T _A =70℃	— P _D —	1.3	VV	
Junction and Storage Temperature Range		T _J , T _{STG}	-55 to 150	C	

Thermal Characteristics					
Parameter	Symbol	Тур	Max	Units	
Maximum Junction-to-Ambient A	t ≤ 10s	D	48	62.5	°C/W
Maximum Junction-to-Ambient AD	Steady-State	R _{θJA}	74	90	°C/W
Maximum Junction-to-Lead	Steady-State	$R_{\theta JL}$	32	40	°C/W





Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Conditions		Min	Тур	Max	Units
STATIC PARAMETERS							
BV _{DSS}	Drain-Source Breakdown Voltage	I _D =250μA, V _{GS} =0V		80			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =80V, V _{GS} =0V				1	
			T_=55℃			5	μA
I _{GSS}	Gate-Body leakage current	V_{DS} =0V, V_{GS} = ±30V				100	nA
V _{GS(th)}	Gate Threshold Voltage	$V_{DS}=V_{GS}$ I _D =250µA		3.5	4.2	5	V
I _{D(ON)}	On state drain current	V_{GS} =10V, V_{DS} =5V		18			А
P	Static Drain-Source On-Resistance				62	75	
R _{DS(ON)}	Static Drain-Source On-Nesistance		T_=125℃		113.0	135	mΩ
g _{FS}	Forward Transconductance	V_{DS} =5V, I_{D} =3.5A			15		S
V _{SD}	Diode Forward Voltage	I _S =1A,V _{GS} =0V			0.77	1	V
I _S	Maximum Body-Diode Continuous Cu	rent				2.5	А
I _{SM}	Pulsed Body-diode Current ^C					18	Α
DYNAMIC	PARAMETERS						
C _{iss}	Input Capacitance				640	770	рF
C _{oss}	Output Capacitance	V _{GS} =0V, V _{DS} =40V, f=1MHz V _{GS} =0V, V _{DS} =0V, f=1MHz		28	40	52	pF
C _{rss}	Reverse Transfer Capacitance			12	20	30	pF
R _g	Gate resistance			0.9	1.8	2.7	Ω
SWITCHI	NG PARAMETERS					-	
Q _g (10V)	Total Gate Charge		V _{GS} =10V, V _{DS} =40V, I _D =3.5A		11	13	nC
Q _g (4.5V)	Total Gate Charge				5.5	7	
Q _{gs}	Gate Source Charge	$V_{GS} = 100, V_{DS} = 400, 1$			5	6	nC
Q _{gd}	Gate Drain Charge	1		0.7	1.2	1.7	nC
t _{D(on)}	Turn-On DelayTime	V_{GS} =10V, V_{DS} =40V, R_{L} =8 Ω , R_{GEN} =3 Ω			7.2		ns
t _r	Turn-On Rise Time				2.2		ns
t _{D(off)}	Turn-Off DelayTime				17		ns
t _f	Turn-Off Fall Time				2		ns
t _{rr}	Body Diode Reverse Recovery Time	I _F =3.5A, dI/dt=300A/µ	us	14	20	26	ns
Q _{rr}	Body Diode Reverse Recovery Charge	_€ I _F =3.5A, dI/dt=300A/µ	JS	35	50	65	nC

A. The value of $R_{\theta JA}$ is measured with the device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25$ °C. The value in any given application depends on the user's specific board design.

B. The power dissipation P_D is based on $T_{J(MAX)}=150$ °C, using ≤ 10 s junction-to-ambient thermal resistance.

C. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150$ °C. Ratings are based on low frequency and duty cycles to keep initial $T_J=25$ °C.

D. The $R_{\theta JA}$ is the sum of the thermal impedence from junction to lead $R_{\theta JL}$ and lead to ambient.

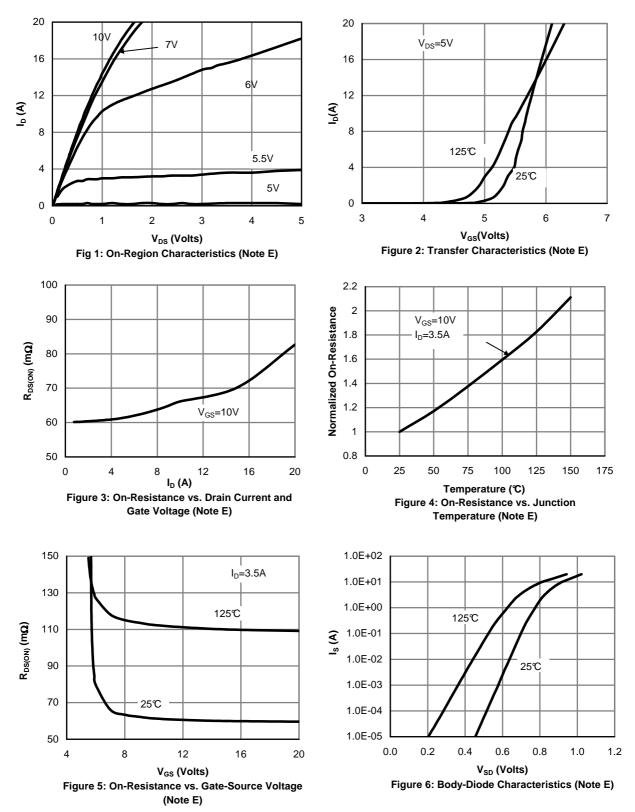
E. The static characteristics in Figures 1 to 6 are obtained using <300 μ s pulses, duty cycle 0.5% max.

F. These curves are based on the junction-to-ambient thermal impedence which is measured with the device mounted on 1in² FR-4 board with



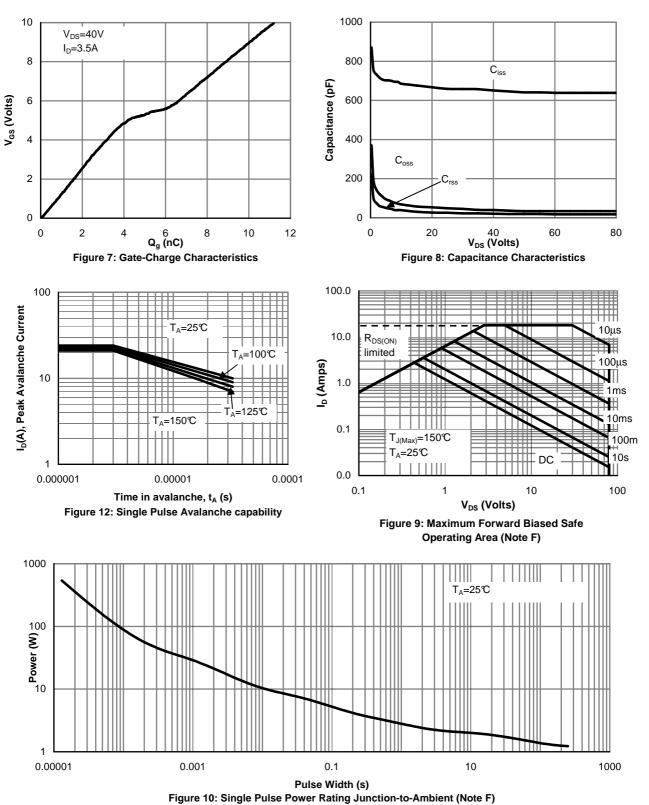
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TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS



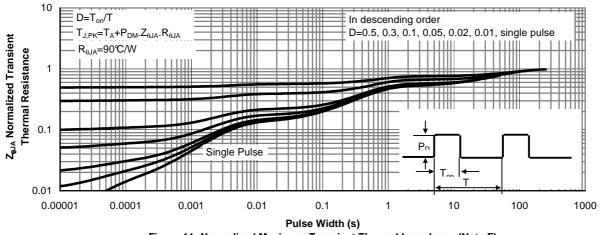


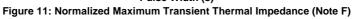
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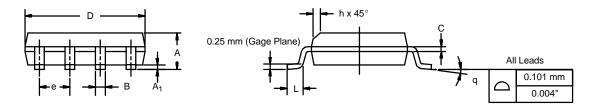


Package Information www.din-tek.jp

SOIC (NARROW): 8-LEAD

JEDEC Part Number: MS-012

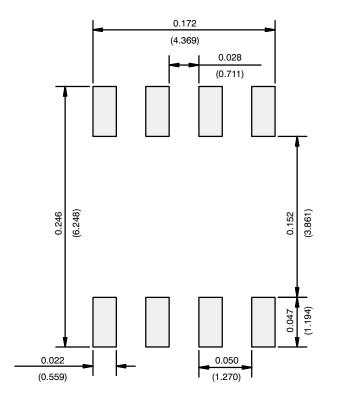




	MILLIMETERS			INCHES		
DIM	Min	Мах	Min	Max		
A	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27 BSC		0.050) BSC		
н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498						



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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